



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In the application of:

Kunihiro TAKATANI

Serial No.: 09/557,961

Filing Date: April 25, 2000

For: ELECTRODE STRUCTURE ON P-TYPE
III GROUP NITRIDE SEMICONDUCTOR
LAYER AND FORMATION METHOD
THEREOF

Examiner: Donghee Kang

Group Art Unit: 2811

AMENDMENT UNDER 37 CFR 1.116

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action dated September 9, 2004, please amend the above-application as follows and consider the following remarks:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 5 of this paper.

*please enter
Amendment AF*